NSN 5962-01-449-6899

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Features Provided:
High speed and static operation and low power
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Hi speed cmos static ram
Voltage Rating And Type Per Characteristic:
5.0 volts total supply
Time Rating Per Chacteristic:
150.00 nanoseconds af output megawatts
Memory Device Type:
Ram
Terminal Type And Quantity:
28 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0